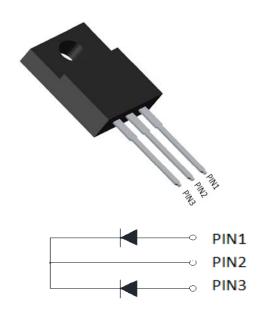


## **Ultra-Fast Recovery Rectifier Diodes**



#### **Features**

- High frequency operation
- High surge forward current capability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

### **Typical Applications**

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

#### **Mechanical Data**

Package: ITO-220AB
 Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant

• **Terminals**: Tin plated leads, solderable per J-STD-002 and JESD22-B102

• Polarity: As marked

### ■Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MUR2010FCT	MUR2015FCT	MUR2020FCT	MUR2040FCT	MUR2060FCT
Device Marking Code			MUR2010FCT	MUR2015FCT	MUR2020FCT	MUR2040FCT	MUR2060FCT
Repetitive Peak Reverse Voltage	VRRM	٧	100	150	200	400	600
Average Rectified Output Current @60Hz half sine-wave, R-load, Tc(FIG.1)	l <sub>0</sub>	Α	20				
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, $T_a$ =25 $^{\circ}$ C	IFSM	Α	125				
Current Squared Time @1ms≤t≤8.3ms Tj=25°C	l <sup>2</sup> t	A <sup>2</sup> s	65				
Storage Temperature	T <sub>stg</sub>	$^{\circ}$	-55 ~ +150				
Junction Temperature	Tj	$^{\circ}$	-55 ~ +150				

#### **■Electrical Characteristics** (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MUR2010FCT	MUR2015FCT	MUR2020FCT	MUR2040FCT	MUR2060FCT
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=10.0A		0.975		1.3	1.5
Maximum DC reverse current at	IRRM1		VRM=VRRM Ta=25°C	10				
rated DC blocking voltage per diode	IRRM2	uA	VRM=VRRM Ta=125°C	500				
Reverse Recovery Time	Trr	ns	I <sub>F</sub> =0.5A I <sub>RM</sub> =1A I <sub>RR</sub> =0.25A	25 50		0		

### **■Thermal Characteristics** (T<sub>a</sub>=25°C Unless otherwise specified)

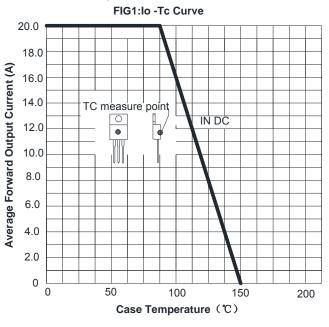
<u> </u>								
PA	RAMETER	SYMBOL	UNIT	MUR2010FCT	MUR2015FCT	MUR2020FCT	MUR2040FCT	MUR2060FCT
Thermal Resistance	Between junction and case	R <sub>θJ-C</sub>	°C/W			2.5		

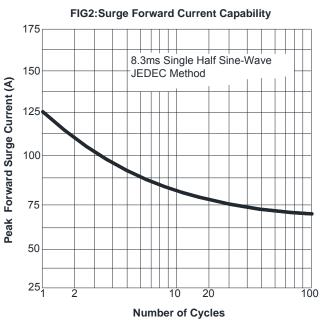


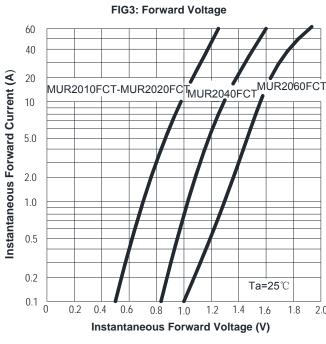
**■Ordering Information** (Example)

PREFERED P/N UNIT WEIGHT(g)		MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MUR20 MUR20 MUR20 MUR20 MUR20 10FCT 15FCT 20FCT 40FCT 60FCT	Approximate 1.48	50	1000	5000	Tube

### **■Characteristics** (Typical)







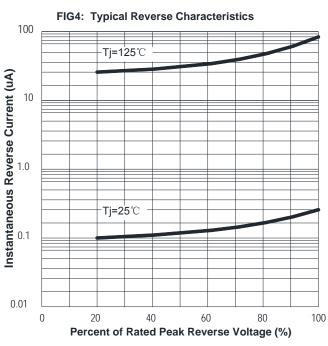
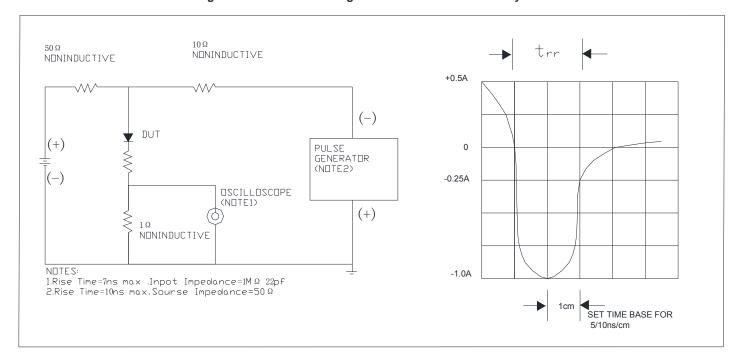
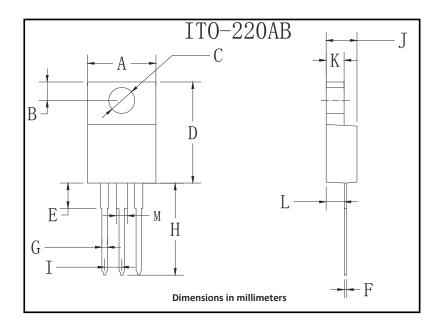




FIG.5 Diagram of circuit and Testing wave form of reverse recovery time



#### **■Outline Dimensions**



ITO-220AB					
Dim	Min	Max			
Α	9.7	10.7			
В	2.15	3.25			
С	2.6	3.8			
D	14.4	15.9			
Е	3.1	4.5			
F	0.4	0.8			
G	0.4	0.8			
Н	12.7	14.2			
I	1.80	2.95			
J	1.4	1.8			
K	2.1	3.56			
L	2.1	3.2			
М	3.9	5.1			



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